

### 1. Scope

The present specifications shall apply to an FMX-4203S.

### 2. Outline

Type	Silicon Diode
Structure	Resin Molded
Applications	High Frequency Rectification

### 3. Flammability

UL94V-0(Equivalent)

## 4. Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	$V_{RSM}$	V	300	
2	Peak Reverse Voltage	$V_{RM}$	V	300	
3	Average Forward Current	$I_{F(AV)}$	A	20	Refer to Derating of 7
4	Peak Surge Forward Current	$I_{FSM}$	A	100	10msec. Half sinewave, one shot
5	$I^2t$ Limiting Value	$I^2t$	$A^2s$	50	$1msec \leq t \leq 10msec$
6	Junction Temperature	$T_j$	$^{\circ}C$	-40~+150	
7	Storage Temperature	$T_{stg}$	$^{\circ}C$	-40~+150	

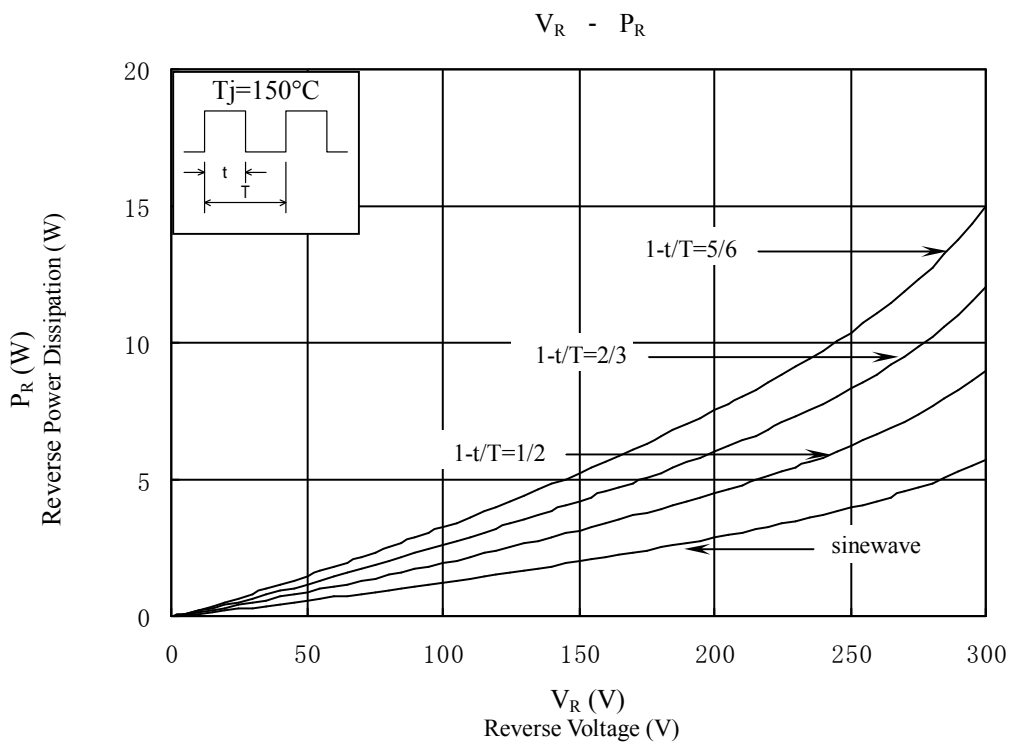
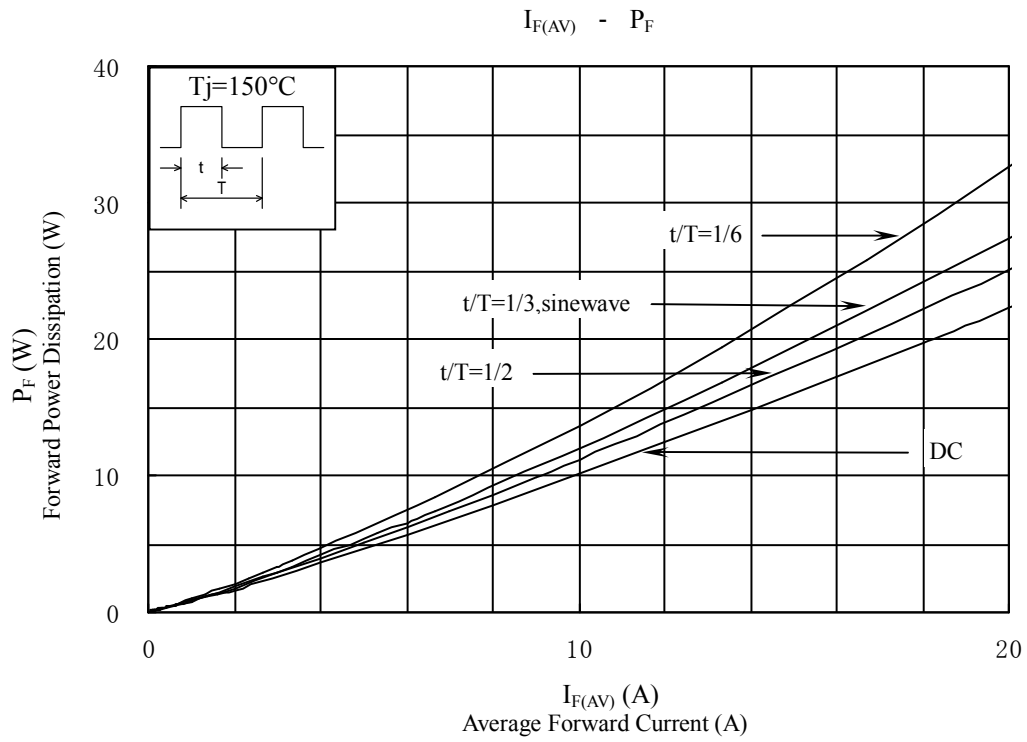
No.1,2,4&5 show ratings per one chip.

5. Electrical characteristics ( $T_a=25^{\circ}C$  , unless otherwise specified)

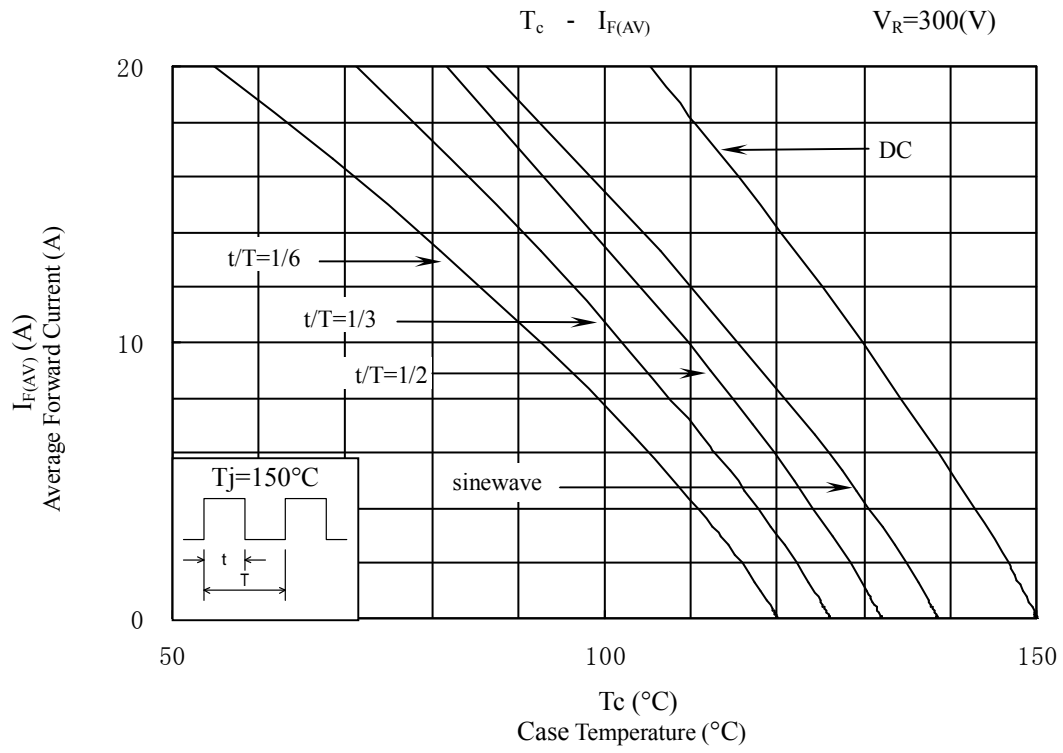
No.	Item	Symbol	Unit	Value	Conditions
1	Forward Voltage Drop	$V_F$	V	1.30 max.	$I_F=10A$
2	Reverse Leakage Current	$I_R$	$\mu A$	100 max.	$V_R=V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H \cdot I_R$	mA	30 max.	$V_R=V_{RM}, T_j=150^{\circ}C$
4	Reverse Recovery Time	trr1	ns	30 max.	$I_F=I_{RP}=500mA$ 90% Recovery point, $T_j=25^{\circ}C$
		trr2	ns	25 max.	$I_F=500mA, I_{RP}=1A$ 75% Recovery point, $T_j=25^{\circ}C$
5	Thermal Resistance	$R_{th(j-c)}$	$^{\circ}C/W$	2.0 max.	Between Junction and case

No.1,2,3&4 show characteristics per one chip.

6. Characteristics

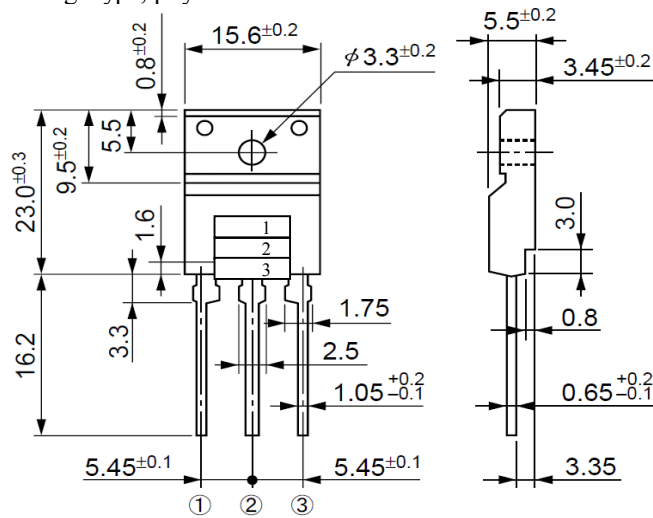


7. Derating



8. Package information

8-1 Package type, physical dimensions and material



: root dimension

tolerance ± 0.2

Dimensions in mm

8-2 Appearance

The body shall be clean and shall not bear any stain, rust or flaw.

8-3 Marking

Type Name	Marking		
	*1 Type Name	*2 Polarity	*3 Lot number
FMX-4203S	X4203S		1st letter: Last digit of year 2nd letter: Month From 1 to 9 for Jan. to Sep., O for Oct., N for Nov., D for Dec. 3rd & 4th letter: Day ex. 7518 (May 18, 2007)